Diode Semiconductor Device - Page 1 of 1



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Inclosure N	flaterial:
Glass	
Overall Ler	ngth:
5.000 inche	S
Terminal L	ength:
1.250 inche	S
Overall Dia	meter:
0.520 inche	S
Mounting I	lethod:
Terminal	
Features P	rovided:
Hermeticall	y sealed case
Semicondu	ictor Material:
Silicon	
Voltage Ra	ting In Volts Per Characteristic:
18000.0 re	verse voltage, peak
Current Ra	ting Per Characteristic:
8.00 amper	es average forward current averaged over a full 60-hz cycle
Maximum	Operating Tempurature Per Measurement Point:
165.0 degre	es celsius ambient air
Terminal T	ype And Quantity:
2 uninsulate	ed wire lead
Specificati	on Data:
80131-relea	se4073 professional/industrial association specification
Shelf Life:	
N/a	
Unit Of Me	asure:
Demilitariz	ation:
No	
Fiig:	
A110a0	